



Chipsmall Limited consists of a professional team with an average of over 10 year of expertise in the distribution of electronic components. Based in Hongkong, we have already established firm and mutual-benefit business relationships with customers from Europe, America and south Asia, supplying obsolete and hard-to-find components to meet their specific needs.

With the principle of "Quality Parts, Customers Priority, Honest Operation, and Considerate Service", our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip, ALPS, ROHM, Xilinx, Pulse, ON, Everlight and Freescale. Main products comprise IC, Modules, Potentiometer, IC Socket, Relay, Connector. Our parts cover such applications as commercial, industrial, and automotives areas.

We are looking forward to setting up business relationship with you and hope to provide you with the best service and solution. Let us make a better world for our industry!



Contact us

Tel: +86-755-8981 8866 Fax: +86-755-8427 6832

Email & Skype: info@chipsmall.com Web: www.chipsmall.com

Address: A1208, Overseas Decoration Building, #122 Zhenhua RD., Futian, Shenzhen, China

N- and P-Channel 20V (D-S) Power MOSFET

FEATURES

- Low $R_{DS(ON)}$ to minimize conductive losses
- Low gate charge for fast power switching
- Compliant to RoHS directive 2011/65/EU and in accordance to WEEE 2002/96/EC
- Halogen-free according to IEC 61249-2-21

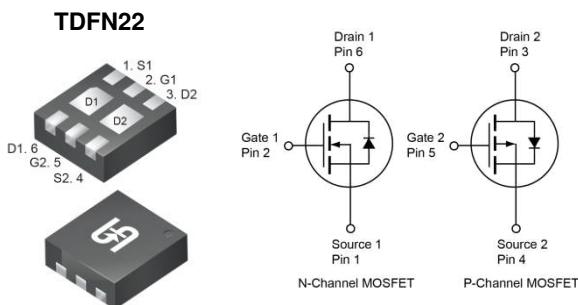
APPLICATIONS

- Load Switch
- Power Management
- Portable Devices

KEY PERFORMANCE PARAMETERS			
PARAMETER	TYPE	VALUE	UNIT
V_{DS}	N-ch	20	V
	P-ch	-20	
$R_{DS(on)}$ (max)	N-ch	30	mΩ
		36	
		42	
	P-ch	55	
		78	
		90	
Q_g	N-ch	9.1	nC
	P-ch	9.8	



ROHS
COMPLIANT
HALOGEN FREE



Note: MSL 3 (Moisture Sensitivity Level) per J-STD-020

ABSOLUTE MAXIMUM RATINGS ($T_A = 25^\circ\text{C}$ unless otherwise noted)

PARAMETER	SYMBOL	N-ch	P-ch	UNIT
Drain-Source Voltage	V_{DS}	20	-20	V
Gate-Source Voltage	V_{GS}	± 12	± 12	V
Continuous Drain Current (Note 1)	I_D	11.6	-9	A
		6.4	-5	
Pulsed Drain Current	I_{DM}	46.4	-36	A
Total Power Dissipation	P_D	6.25	6.25	W
		1.25	1.25	
Total Power Dissipation	P_D	1.89	1.89	W
		0.38	0.38	
Operating Junction and Storage Temperature Range	T_J, T_{STG}	-55 to +150		°C

THERMAL PERFORMANCE

PARAMETER	SYMBOL	LIMIT	UNIT
Thermal Resistance – Junction to Case	R_{EJC}	20	°C/W
Thermal Resistance – Junction to Ambient	R_{EJA}	66	

Thermal Performance Note: R_{EJA} is the sum of the junction-to-case and case-to-ambient thermal resistances. The case-thermal reference is defined at the solder mounting surface of the drain pins. R_{EJA} is guaranteed by design while R_{ECA} is determined by the user's board design.

ELECTRICAL SPECIFICATIONS ($T_A = 25^\circ\text{C}$ unless otherwise noted)							
PARAMETER	CONDITIONS	SYMBOL	TYPE	MIN	TYP	MAX	UNIT
Static							
Drain-Source Breakdown Voltage	$V_{GS} = 0V, I_D = 250\mu\text{A}$	BV_{DSS}	N-ch	20	--	--	V
	$V_{GS} = 0V, I_D = -250\mu\text{A}$		P-ch	-20	--	--	
Gate Threshold Voltage	$V_{GS} = V_{DS}, I_D = 250\mu\text{A}$	$V_{GS(\text{TH})}$	N-ch	0.5	0.8	1	V
	$V_{GS} = V_{DS}, I_D = -250\mu\text{A}$		P-ch	-0.45	-0.7	-1	
Gate-Source Leakage Current	$V_{GS} = \pm 12V, V_{DS} = 0V$	I_{GSS}	N-ch	--	--	± 100	nA
	$V_{GS} = \pm 12V, V_{DS} = 0V$		P-ch	--	--	± 100	
Drain-Source Leakage Current	$V_{GS} = 0V, V_{DS} = 20V$	I_{DSS}	N-ch	--	--	1	μA
	$V_{GS} = 0V, V_{DS} = 20V$			--	--	100	
	$T_J = 125^\circ\text{C}$		P-ch	--	--	-1	
	$V_{GS} = 0V, V_{DS} = -20V$			--	--	-100	
	$V_{GS} = 0V, V_{DS} = -20V$			--	--	125°C	
Drain-Source On-State Resistance ^(Note 2)	$V_{GS} = 4.5V, I_D = 6.4A$	$R_{DS(\text{on})}$	N-ch	--	17	30	$\text{m}\Omega$
	$V_{GS} = 2.5V, I_D = 5.8A$			--	22	36	
	$V_{GS} = 1.8V, I_D = 5.4A$			--	32	42	
	$V_{GS} = -4.5V, I_D = -5A$		P-ch	--	48	55	
	$V_{GS} = -2.5V, I_D = -4.2A$			--	60	78	
	$V_{GS} = -1.8V, I_D = -3.9A$			--	78	90	
Forward Transconductance ^(Note 2)	$V_{DS} = 5V, I_D = 6.4A$	g_{fs}	N-ch	--	28	--	S
	$V_{DS} = -5V, I_D = -5A$		P-ch	--	15	--	
Dynamic ^(Note 3)							
Total Gate Charge	$N\text{-ch}$ $V_{GS} = 4.5V,$ $V_{DS} = 10V, I_D = 6.4A$	Q_g	N-ch	--	9.1	--	nC
			P-ch	--	9.8	--	
Gate-Source Charge	$P\text{-ch}$	Q_{gs}	N-ch	--	1.3	--	nC
			P-ch	--	1.1	--	
Gate-Drain Charge	$V_{GS} = -4.5V,$ $V_{DS} = -10V, I_D = -5A$	Q_{gd}	N-ch	--	2.7	--	nC
			P-ch	--	2.7	--	
Input Capacitance	$N\text{-ch}$ $V_{GS} = 0V, V_{DS} = 10V$ $f = 1.0\text{MHz}$	C_{iss}	N-ch	--	677	--	pF
			P-ch	--	744	--	
Output Capacitance	$P\text{-ch}$	C_{oss}	N-ch	--	120	--	pF
			P-ch	--	106	--	
Reverse Transfer Capacitance	$V_{GS} = 0V, V_{DS} = -10V$ $f = 1.0\text{MHz}$	C_{rss}	N-ch	--	89	--	pF
			P-ch	--	97	--	
Gate Resistance	$f = 1.0\text{MHz}$	R_g	N-ch	--	3	--	Ω
			P-ch	--	80	--	

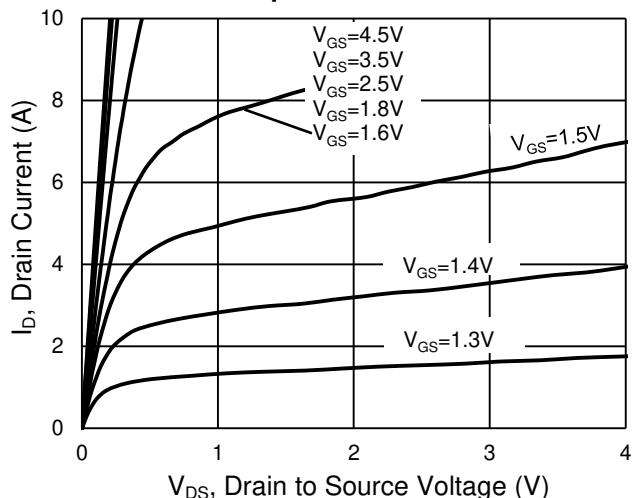
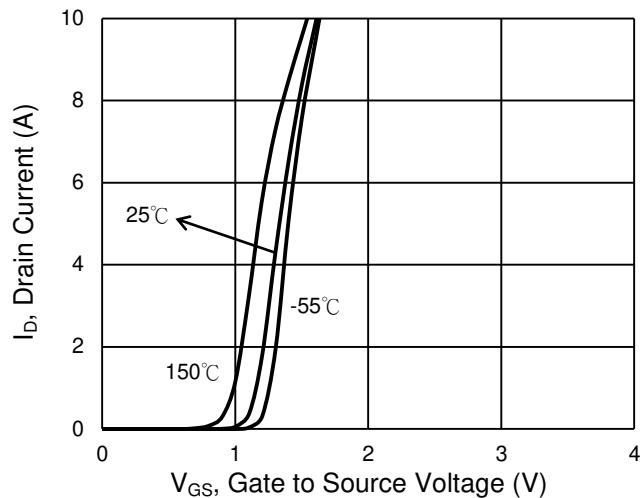
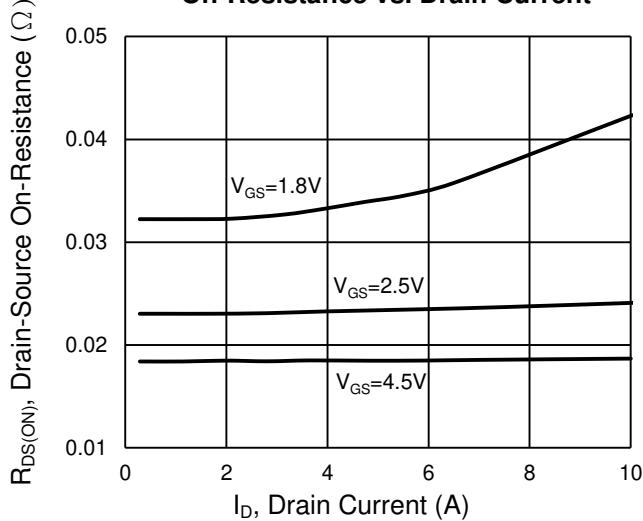
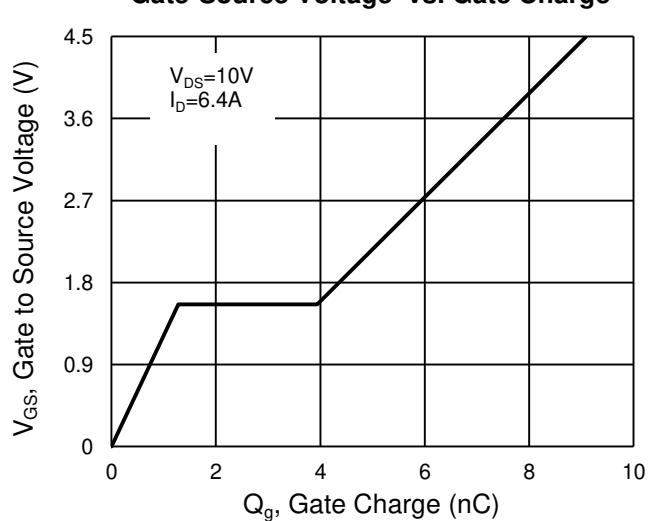
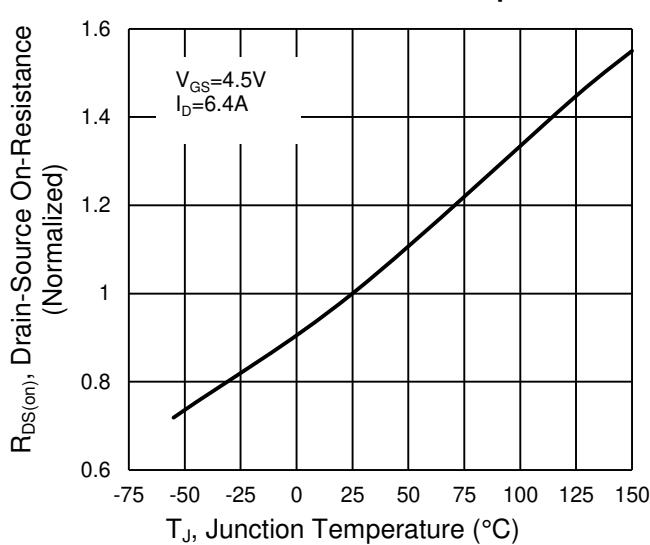
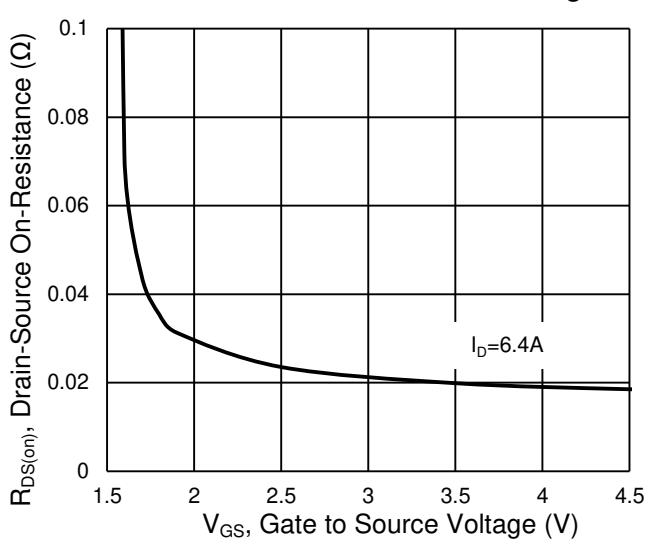
ELECTRICAL SPECIFICATIONS ($T_A = 25^\circ\text{C}$ unless otherwise noted)							
PARAMETER	CONDITIONS	SYMBOL	TYPE	MIN	TYP	MAX	UNIT
Switching <small>(Note 3)</small>							
Turn-On Delay Time Turn-On Rise Time Turn-Off Delay Time Turn-Off Fall Time	N-ch $V_{GS} = 4.5V, R_G = 2\Omega$ $V_{DS} = 10V, I_D = 6.4A$	$t_{d(on)}$	N-ch	--	8	--	ns
			P-ch	--	10	--	
	P-ch $V_{GS} = -4.5V, R_G = 2\Omega$ $V_{DS} = -10V, I_D = -5A$	t_r	N-ch	--	41	--	
			P-ch	--	34	--	
	N-ch $V_{GS} = -4.5V, R_G = 2\Omega$ $V_{DS} = -10V, I_D = -5A$	$t_{d(off)}$	N-ch	--	25	--	
			P-ch	--	69	--	
		t_f	N-ch	--	30	--	
			P-ch	--	68	--	
Source-Drain Diode							
Forward Voltage <small>(Note 2)</small>	$V_{GS} = 0V, I_S = 6.4A$	V_{SD}	N-ch	--	0.7	--	V
	$V_{GS} = 0V, I_S = -5A$		P-ch	--	-0.8	--	
Reverse recovery Time Reverse Recovery Charge	N-ch $I_S = 6.4A,$ $dI/dt=100A/\mu s$	t_{rr}	N-ch	--	22	--	nc
			P-ch	--	113	--	
	P-ch $I_S = -5A,$ $dI/dt=100A/\mu s$	Q_{rr}	N-ch	--	6	--	nc
			P-ch	--	160	--	

Notes:

1. Silicon limited current only.
2. Pulse test: Pulse Width $\leq 300\mu s$, duty cycle $\leq 2\%$.
3. Switching time is essentially independent of operating temperature.

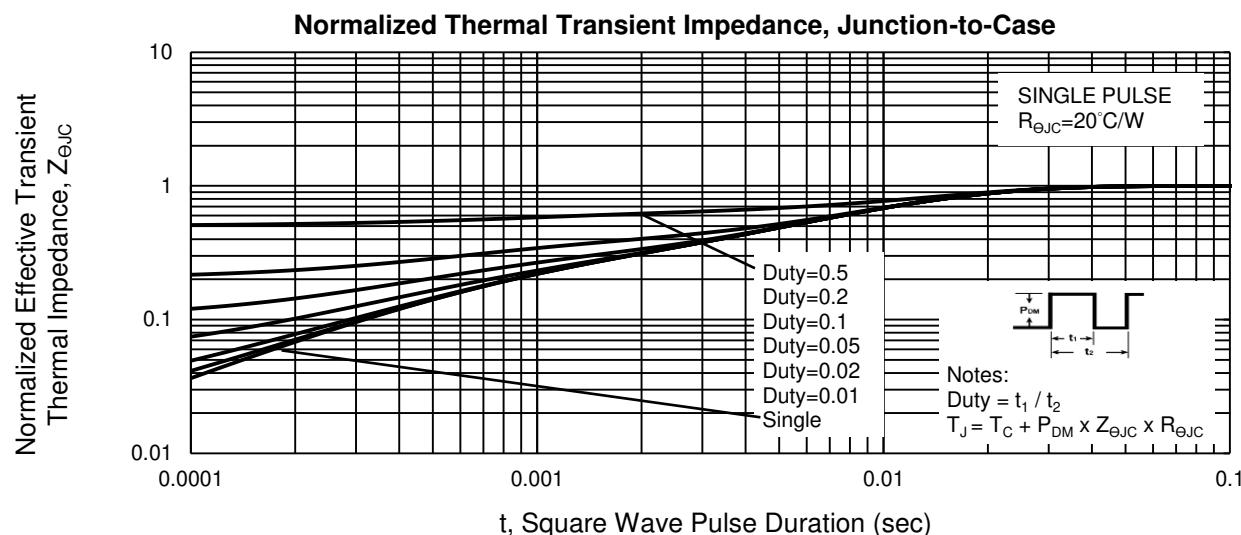
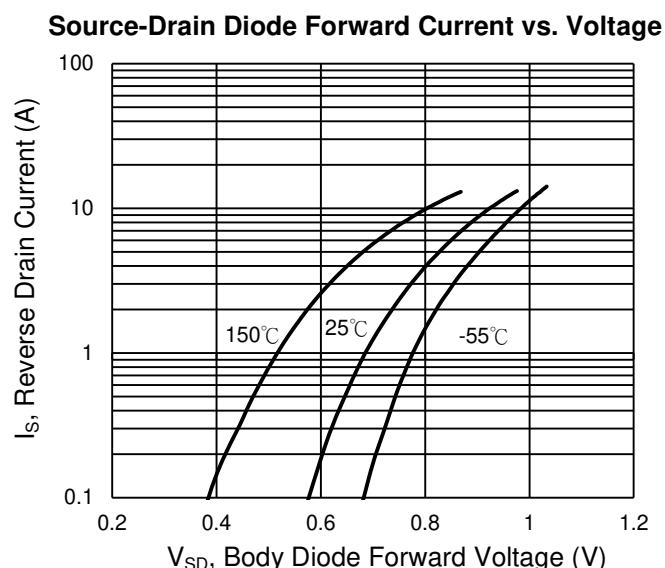
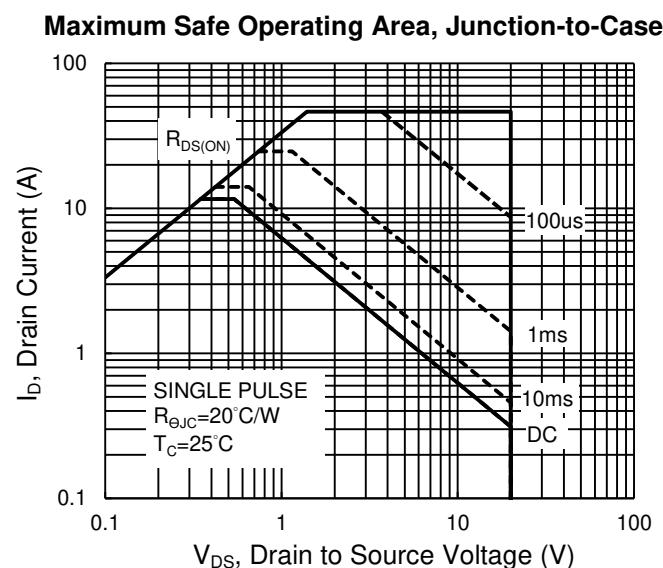
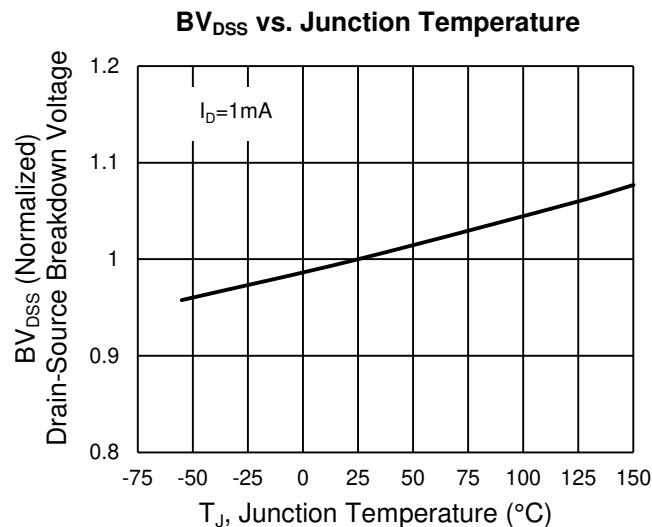
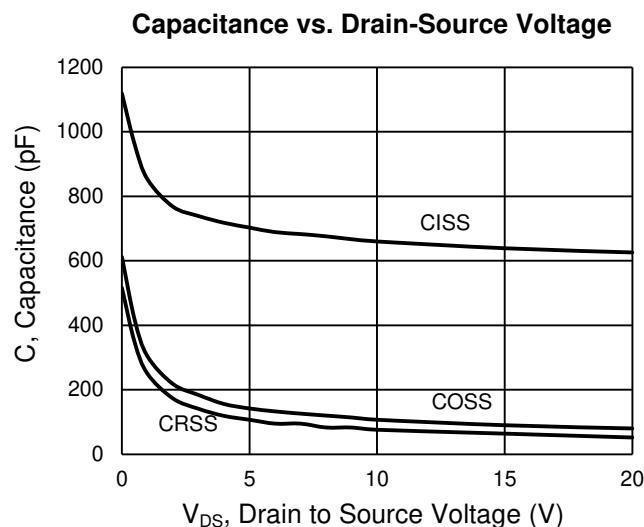
ORDERING INFORMATION

PART NO.	PACKAGE	PACKING
TSM2537CQ RFG	TDFN22	3,000pcs / 7" Reel

CHARACTERISTICS CURVES (N-Channel)
 $(T_A = 25^\circ\text{C} \text{ unless otherwise noted})$
Output Characteristics

Transfer Characteristics

On-Resistance vs. Drain Current

Gate-Source Voltage vs. Gate Charge

On-Resistance vs. Junction Temperature

On-Resistance vs. Gate-Source Voltage


CHARACTERISTICS CURVES (N-Channel)

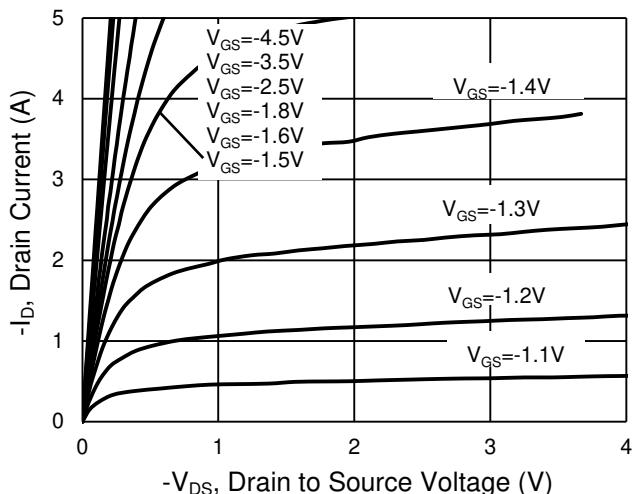
($T_A = 25^\circ\text{C}$ unless otherwise noted)



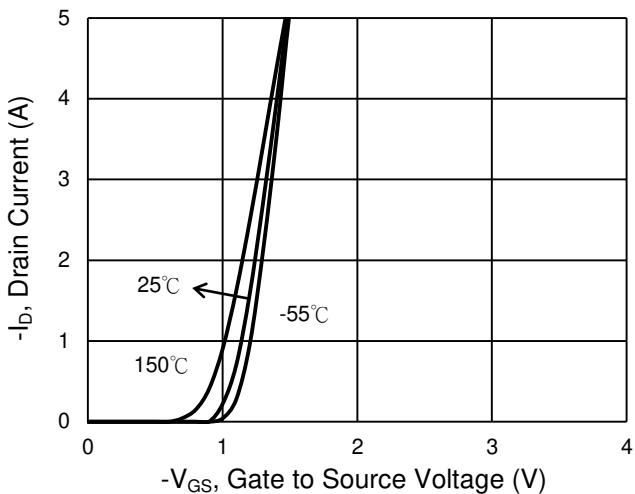
CHARACTERISTICS CURVES (P-Channel)

($T_A = 25^\circ\text{C}$ unless otherwise noted)

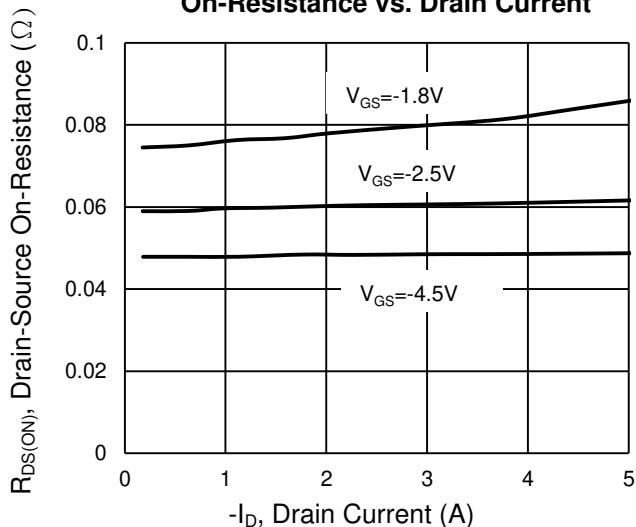
Output Characteristics



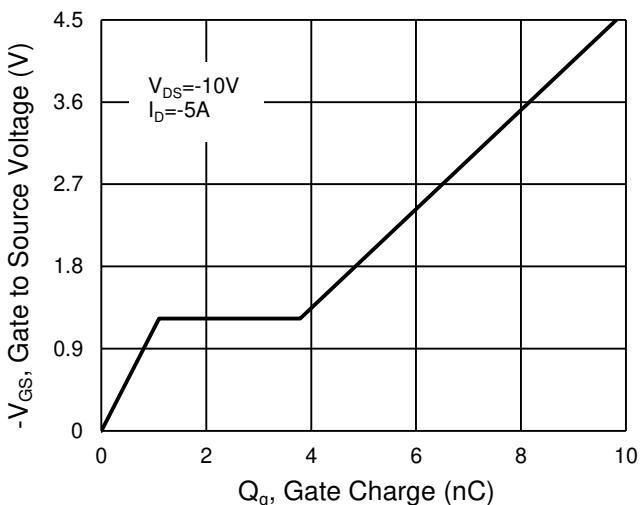
Transfer Characteristics



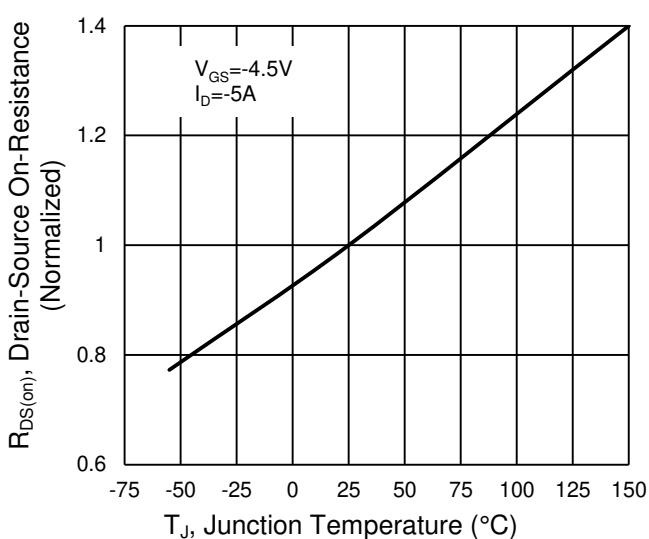
On-Resistance vs. Drain Current



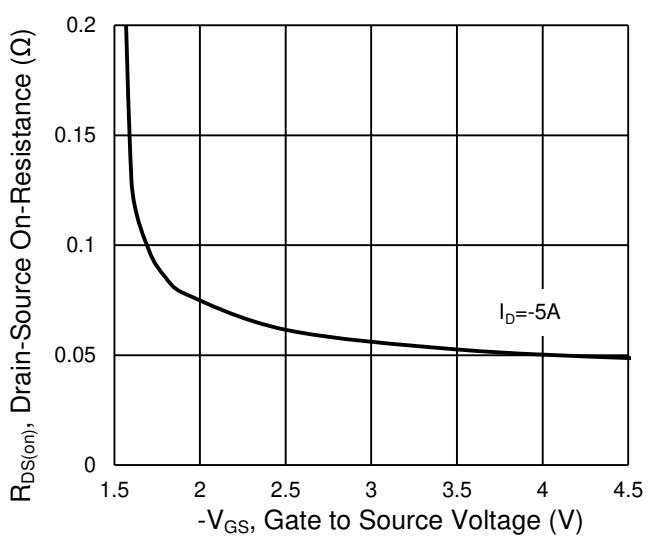
Gate-Source Voltage vs. Gate Charge



On-Resistance vs. Junction Temperature

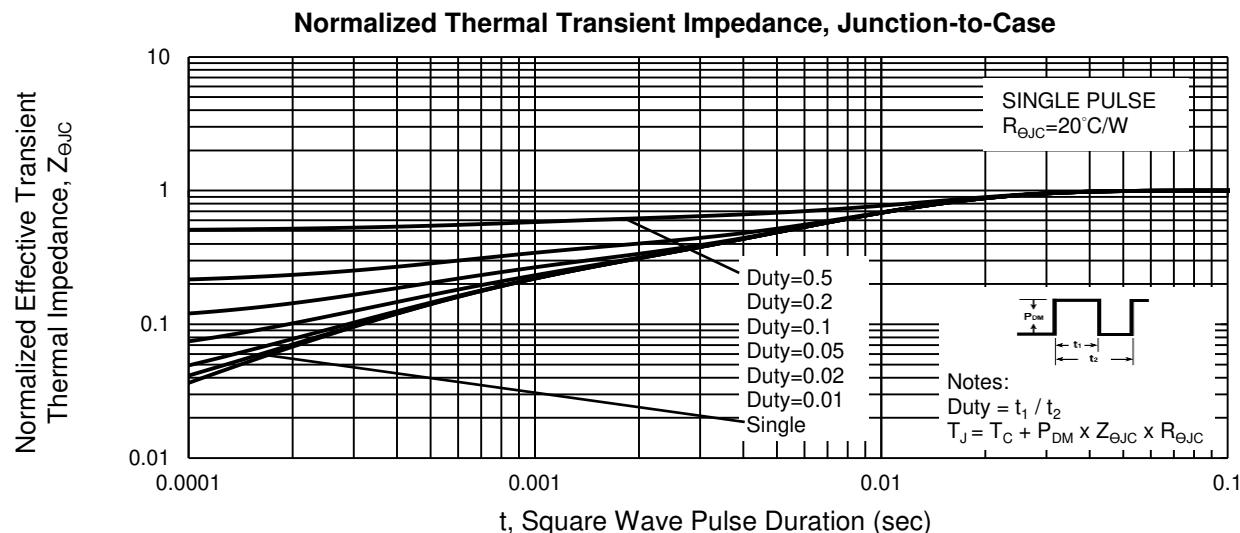
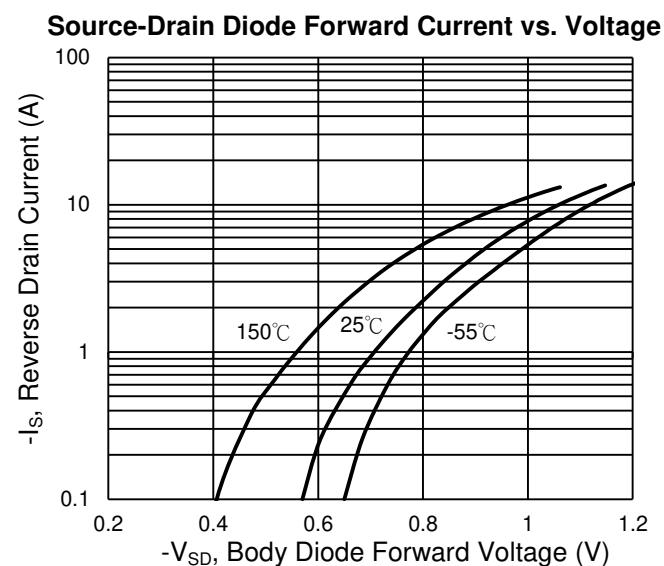
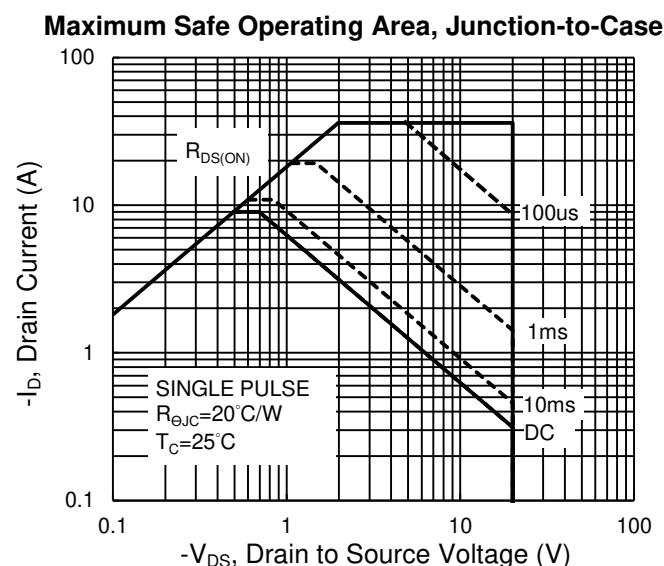
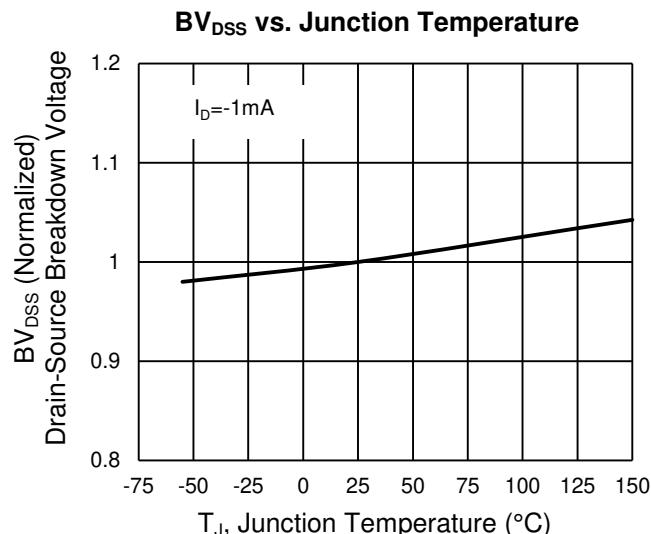
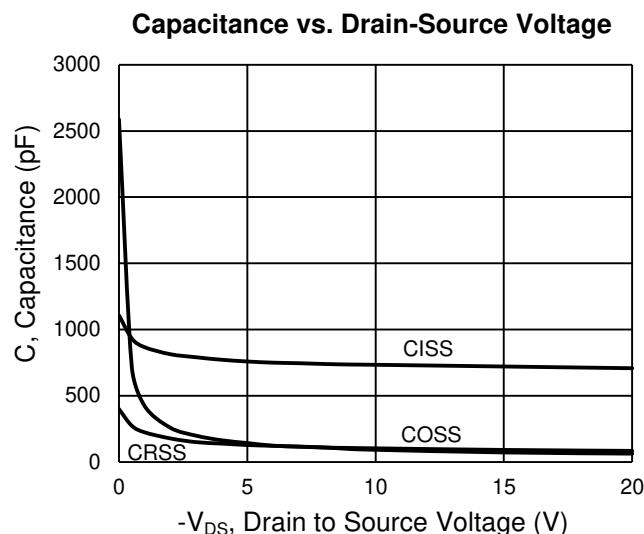


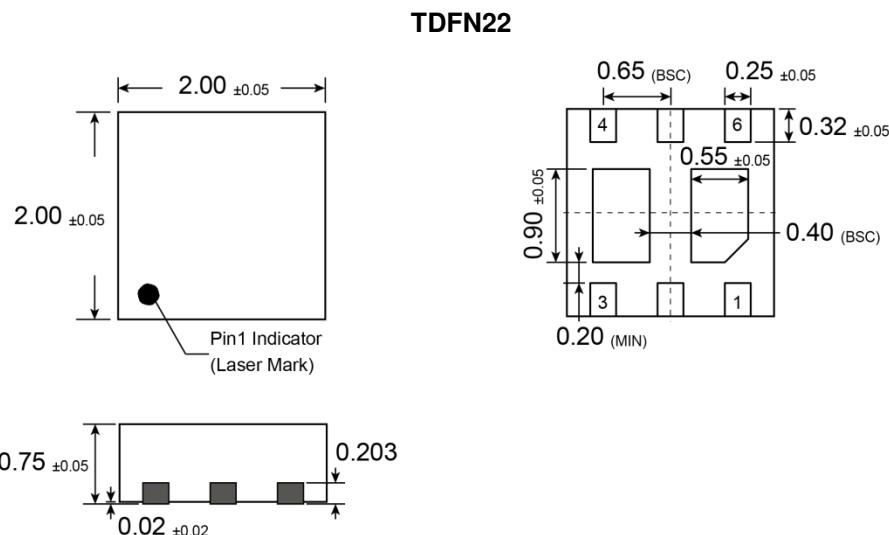
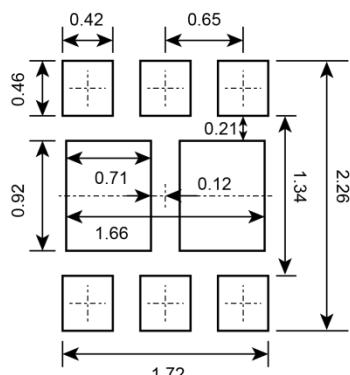
On-Resistance vs. Gate-Source Voltage



CHARACTERISTICS CURVES (P-Channel)

($T_A = 25^\circ\text{C}$ unless otherwise noted)



PACKAGE OUTLINE DIMENSIONS (Unit: Millimeters)

SUGGESTED PAD LAYOUT (Unit: Millimeters)

MARKING DIAGRAM


Y = Year Code

M = Month Code for Halogen Free

O =Jan **P** =Feb **Q** =Mar **R** =Apr

S =May **T** =Jun **U** =Jul **V** =Aug

W =Sep **X** =Oct **Y** =Nov **Z** =Dec

L = Lot Code (1~9, A~Z)

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